



## ES1A THRU ES1G

### SURFACE MOUNT SUPER FAST SWITCHING RECTIFIER

TECHNICAL SPECIFICATION

**VOLTAGE: 50 TO 400V CURRENT: 1.0A**

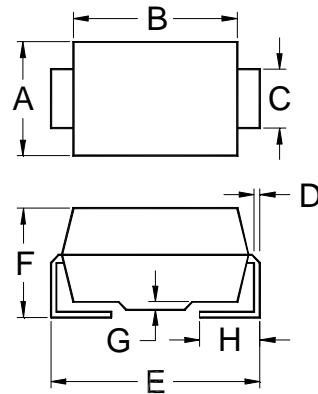
#### FEATURES

- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- Glass passivated chip
- Super fast recovery for high efficiency
- High temperature soldering guaranteed: 260°C/10sec/at terminal

#### MECHANICAL DATA

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode

#### SMA/DO-214AC



	A	B	C	D
MAX.	.110(2.79)	.177(4.50)	.058(1.47)	.012(0.305)
MIN.	.100(2.54)	.157(3.99)	.052(1.32)	.006(0.152)
	E	F	G	H
MAX.	.208(5.28)	.090(2.29)	.008(0.203)	.060(1.52)
MIN.	.194(4.93)	.078(1.98)	.004(0.102)	.030(0.76)

Dimensions in inches and (millimeters)

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	ES1A	ES1B	ES1C	ES1D	ES1E	ES1G	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	V
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	V
Maximum Average Forward Rectified Current ( $T_L=110^\circ\text{C}$ )	$I_{F(AV)}$	1.0						A
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	$I_{FSM}$	30						A
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_F$	0.95			1.25			V
Maximum DC Reverse Current ( $T_a=25^\circ\text{C}$ )	$I_R$	5.0						$\mu\text{A}$
(at rated DC blocking voltage) ( $T_a=100^\circ\text{C}$ )		200						$\mu\text{A}$
Maximum Reverse Recovery Time (Note 1)	$t_{rr}$	35						nS
Typical Junction Capacitance (Note 2)	$C_J$	10						pF
Typical Thermal Resistance (Note 3)	$R_\theta(ja)$	40						$^\circ\text{C/W}$
Storage and Operation Junction Temperature	$T_{STG}, T_J$	-50 to +150						$^\circ\text{C}$

Note:

- 1.Reverse recovery condition  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{rr}=0.25\text{A}$ .
- 2.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 3.Thermal resistance from junction to terminal mounted on 5x5mm copper pad area